C0864 Computer Organization and Architecture

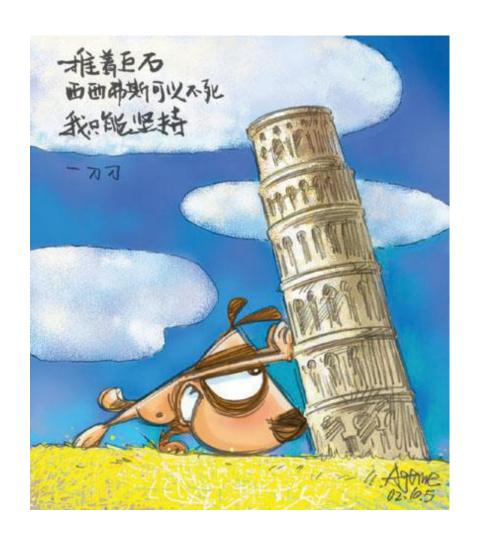


Lecture 12

Mid-term Review

Congwei Ren
Software Institute, Nanjing University
Apr. 29, 2014





Concept

Computer

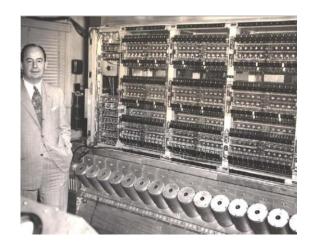


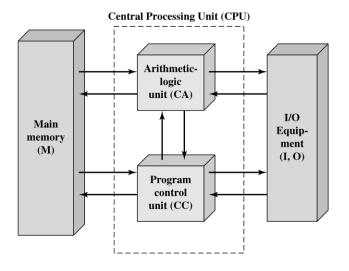
- General-purpose electronic digital computer
- Architecture (visible to programmer)
 - The attributes have a direct impact on the logical execution of a program
 - Instruction set, the number of bits to represent data type, ...
 - E.g.: Is there a multiply instruction?
- Organization (transparent to programmer)
 - The operational units and their interconnections
 - Control signals, memory technology, ...
 - E.g.: Implement multiply by a hardware unit or repeated addition?



The von Neumann machine

- Idea: main memory storing programs and data
- Prototype of all subsequent computers
 - Central Arithmetical (CA)
 - Central Control (CC)
 - Memory (M)
 - Input (I) / Output (O)





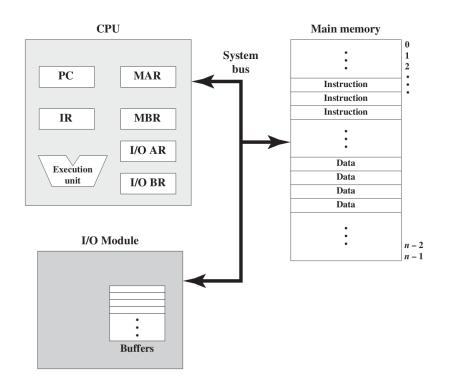


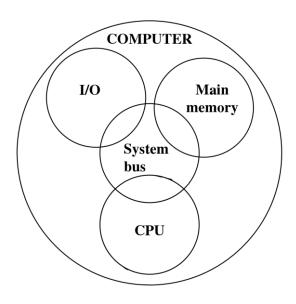
Computer Performance

- Performance evaluation
 - CPU: speed
 - Memory: capacity, speed
 - I/O: speed, capacity
- The main goal / driver is the increase of CPU speed
 - System clock

- Instruction execution
- Million Instructions Per Second (MIPS)
- Million Floating Point Operations Per Second (MFLOPS)

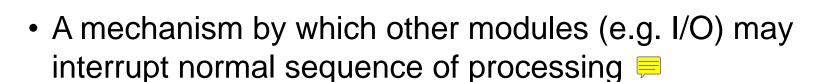
Computer Components



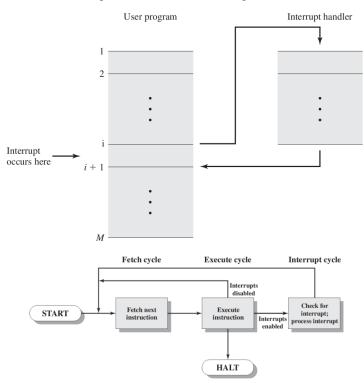


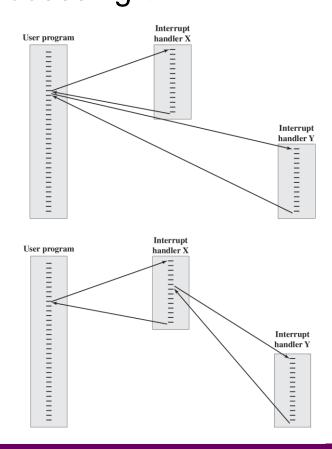


CPU: Interrupt



Multiple interrupts





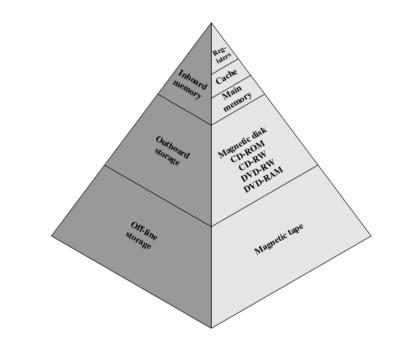


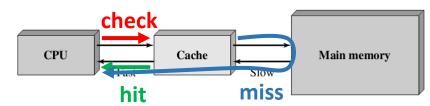
7

Memory: Cache

Principle

- -
- Average access time =
- Design elements
 - Cache size
 - Mapping function =
 - Replacement algorithm =
 - Write policy =
 - Line size
 - Number of caches



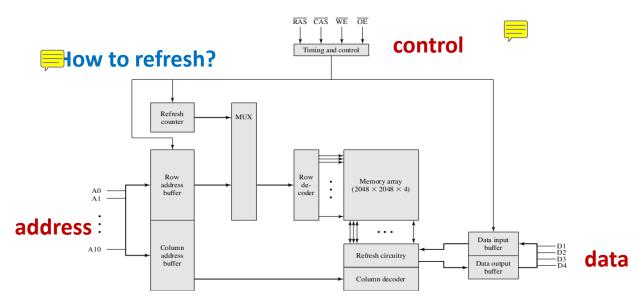




Memory: Main Memory

- Memory cell
- Semiconductor memory types
- Memory array

Memory Type	Category	Erasure	Write Mechanism	Volatility
Random-access memory (RAM)	Read-write memory	Electrically, byte-level	Electrically	Volatile
Read-only memory (ROM)	Read-only	Not possible	Masks	
Programmable ROM (PROM)	memory		Electrically	Nonvolatile
Erasable PROM (EPROM)		UV light, chip-level		
Electrically Erasable PROM (EEPROM)	Read-mostly memory	Electrically, byte-level		
Flash memory		Electrically, block-level		

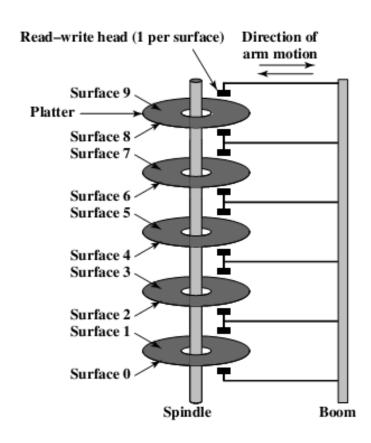


How to select?

NAME OF THE PARTY OF THE PARTY

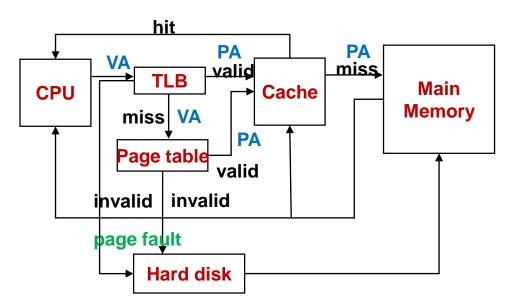
Memory: External Memory

- Magnetic disk
 - Data organization, formatting, read and write mechanism, physical characteristics, =
 timing of a disk transfer
 - Timing of a disk transfer
- Optical memory
- Magnetic tape
 - Parallel vs. serial



Memory: Virtual Memory =

- Partitioning vs. paging =
- Virtual memory
 - Size of page
 - Mapping function
 - Write policy
 - TLB



NANUTO UTATION

Memory: Error



- Basic idea
 - Add some bits to store additional information for correction
- Process
- Type
 - Parity checking
 - Hamming code
 - Cyclic redundancy check

Memory: RAID



- Redundant Array of Independent Disks
- Basic idea
- Characteristic

Category	Level	Description	Disks Required	Data Availability	Large I/O Data Transfer Capacity	Small I/O Request Rate
Striping	0	Nonredundant	N	Lower than single disk	Very high	Very high for both read and write
Mirroring	1	Mirrored	2 <i>N</i>	Higher than RAID 2, 3,4, or 5; lower than RAID 6	Higher than single disk for read; similar to sin- gle disk for write	Up to twice that of a single disk for read; similar to single disk for write
Parallel access	2	Redundant via Ham- ming code	N + m	Much higher than single disk; comparable to RAID 3, 4, or 5	Highest of all listed alternatives	Approximately twice that of a single disk
	3	Bit-interleaved parity	N + 1	Much higher than single disk; comparable to RAID 2, 4, or 5	Highest of all listed alternatives	Approximately twice that of a single disk
Independent access	4	Block-interleaved parity	N + 1	Much higher than single disk; comparable to RAID 2, 3, or 5	Similar to RAID 0 for read; significantly lower than single disk for write	Similar to RAID 0 for read; significantly lower than single disk for write
	5	Block-interleaved distributed parity	N + 1	Much higher than single disk; comparable to RAID 2, 3, or 4	Similar to RAID 0 for read; lower than single disk for write	Similar to RAID 0 for read; generally lower than single disk for write
	6	Block-interleaved dual distributed parity	N + 2	Highest of all listed alternatives	Similar to RAID 0 for read; lower than RAID 5 for write	Similar to RAID 0 for read; significantly lower than RAID 5 for write



1/0



- External device
- I/O module: function, evolution, structure
- I/O operation technique
 - Programmed I/O
 - Interrupt driven I/O
 - Direct memory access
- External interface: serial vs. parallel

Bus

- A communication pathway connecting two or more devices
- Key characteristic
- Component
- Design elements
 - Bus type
 - Arbitration: daisy chain, query by a counter, independently request, self selection, collision detection
 - Timing: synchronous, asynchronous, semi-synchronous, split bus transaction
 - Bus bandwidth and data transfer rate
 - Bus hierar



Thank You

